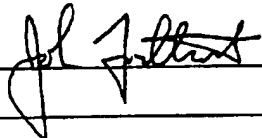


Application Serial No. 10/051,494
Docket No.: SC114492K

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:) Examiner: G. Fourson III
Passlack et al.) Group Art Unit: 2823
Serial No.: 10/051,494)
Filed: January 18, 2002)
For: ARTICLE COMPRISING AN)
OXIDE LAYER ON A GaAs-BASED)
SEMICONDUCTOR STRUCTURE AND)
METHOD OF FORMING SAME)

#7/c
7/11/03
Jm

CERTIFICATION OF FACSIMILE TRANSMISSION	
I hereby certify that this paper is being transmitted via facsimile to the Patent and Trademark Office on the date shown below.	
7-1-03	
Date	
Printed Name	
John A. Fortkort	

RESPONSE AND AMENDMENT

FAX RECEIVED

Honorable Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

JUL 01 2003
TECHNOLOGY CENTER 2800

Sir:

This paper is being submitted in response to the Office
Action dated April 7, 2003.

Amendments to the Specification: No amendments to the
specification are included with this response.

Amendments to the Claims are reflected in the listing of
claims which begins on Page 3 of this paper.

07/14/2003 JTWILLIA1 00000002 502583 10051494
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Application Serial No. 10/051,494
Docket No.: SC114492K

Amendments to the Drawings: No amendments to the drawings
are included with this response.

Remarks/Arguments begin on page 8 of this paper.